

# PDTC143X/123J/143Z/114Y/124XQB

Series

50 V, 100 mA NPN resistor-equipped transistors

Rev. 1 — 1 October 2021 Pro

**Product data sheet** 

# 1. General description

100 mA NPN Resistor-Equipped Transistor (RET) family in an ultra small DFN1110D-3 (SOT8015) leadless Surface-Mounted Device (SMD) plastic package with side-wettable flanks.

**Table 1. Product overview** 

Type number	R1	R2		Package	PNP complement:
	kΩ	kΩ	Nexperia	JEDEC	
PDTC143XQB	4.7	10	SOT8015	MO-340BA	PDTA143XQB
PDTC123JQB	2.2	47			PDTA123JQB
PDTC143ZQB	4.7	47			PDTA143ZQB
PDTC114YQB	10	47			PDTA114YQB
PDTC124XQB	22	47			PDTA124XQB

### 2. Features and benefits

- 100 mA output current capability
- **Built-in resistors**
- Simplifies circuit design
- Reduces component count
- Reduces pick and place costs
- Low package height of 0.5 mm
- Suitable for Automatic Optical Inspection (AOI) of solder joint

# 3. Applications

- Digital applications
- Cost saving alternative for BC847 series in digital applications
- Controlling IC inputs
- Switching loads

#### 4. Quick reference data

#### Table 2. Quick reference data

 $T_{amb}$  = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{CEO}$	collector-emitter voltage	open base	-	-	50	V
Io	output current		-	-	100	mA



# 5. Pinning information

#### **Table 3. Pinning**

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	I	input (base)		
2	GND	GND (emitter)	3	R1
3	0	output (collector)		R2
			1 2	GND
			Transparent top view	aaa-019964

# 6. Ordering information

**Table 4. Ordering information** 

Type number	Package					
	Name	Version				
PDTC143XQB	DFN1110D-3	plastic leadless extremely thin small outline package with	SOT8015			
PDTC123JQB		side-wettable flanks (SWF); 3 terminals; 0.65 mm pitch; body: 1.1 x 1.0 x 0.48 mm				
PDTC143ZQB		body. 1.1 × 1.0 × 0.40 mm				
PDTC114YQB						
PDTC124XQB						

# 7. Marking

Table 5. Marking

Type number	Marking code
PDTC143XQB	E7
PDTC123JQB	E3
PDTC143ZQB	E8
PDTC114YQB	E2
PDTC124XQB	E5

# 8. Limiting values

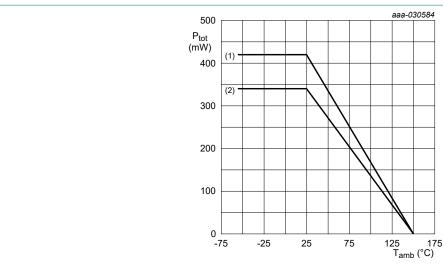
#### Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

T<sub>amb</sub> = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions		Min	Max	Unit			
V <sub>CBO</sub>	collector-base voltage	open emitter		-	50	V			
V <sub>CEO</sub>	collector-emitter voltage	open base		-	50	V			
V <sub>EBO</sub>	emitter-base voltage		,			'			
	PDTC143XQB	open collector		-	7	V			
	PDTC123JQB			-	5	V			
	PDTC143ZQB			-	5	V			
	PDTC114YQB			-	6	V			
	PDTC124XQB			-	7	V			
V <sub>I</sub>	input voltage								
	PDTC143XQB			-7	+30	V			
	PDTC123JQB			-5	+12	V			
	PDTC143ZQB			-5	+30	V			
	PDTC114YQB			-6	+40	V			
	PDTC124XQB			-7	+40	V			
l <sub>o</sub>	output current			-	100	mA			
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1]	-	340	mW			
			[2]	-	420	mW			
T <sub>j</sub>	junction temperature			-	150	°C			
T <sub>amb</sub>	ambient temperature			-55	150	°C			
T <sub>stg</sub>	storage temperature			-65	150	°C			

- [1] Device mounted on an FR4 Printed-Circuit-Board (PCB); single-sided; 35 µm copper; tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB; single-sided; 70 µm copper; tin-plated and standard footprint.



(1) FR4 PCB; single-sided; 70 µm copper; standard footprint

(2) FR4 PCB; single-sided; 35  $\mu m$  copper; standard footprint

Fig. 1. Power derating curves

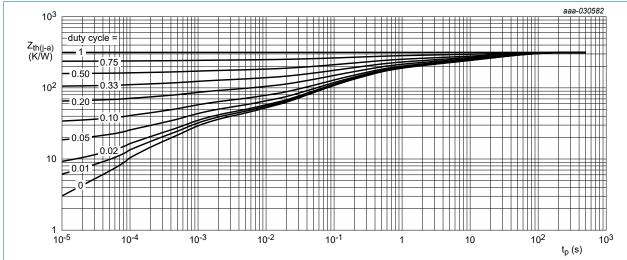
### 9. Thermal characteristics

#### **Table 7. Thermal characteristics**

 $T_{amb}$  = 25 °C unless otherwise specified.

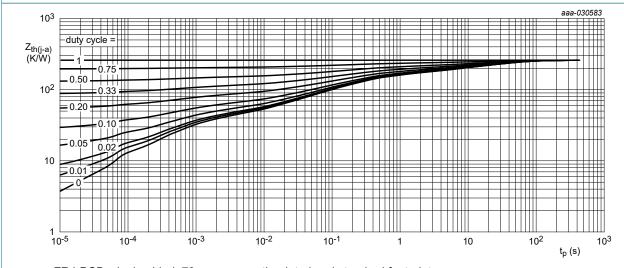
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	368	K/W
			[2]	-	-	298	K/W

- [1] Device mounted on an FR4 PCB; single-sided; 35 μm copper; tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB; single-sided; 70 μm copper; tin-plated and standard footprint.



FR4 PCB; single-sided; 35 µm copper; tin-plated and standard footprint.

Fig. 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB; single-sided; 70 µm copper; tin-plated and standard footprint.

Fig. 3. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

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# 10. Characteristics

#### **Table 8. Characteristics**

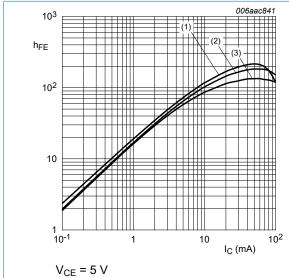
 $T_{amb}$  = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit	
$V_{(BR)CBO}$	collector-base breakdown voltage	$I_C = 100 \mu A; I_E = 0 A$	50	-	-	V	
V <sub>(BR)CEO</sub>	collector-emitter breakdown voltage	$I_C = 2 \text{ mA}; I_B = 0 \text{ A}$	50	-	-	V	
I <sub>CBO</sub>	collector-base cut-off current	V <sub>CB</sub> = 50 V; I <sub>E</sub> = 0 A	-	-	100	nA	
I <sub>CEO</sub>	collector-emitter cut-off	V <sub>CE</sub> = 30 V; I <sub>B</sub> = 0 A	-	-	100	nA	
	current	V <sub>CE</sub> = 30 V; I <sub>B</sub> = 0 A; T <sub>j</sub> = 150 °C	-	-	5	μΑ	
I <sub>EBO</sub>	emitter-base cut-off curr	ent					
	PDTC143XQB	V <sub>EB</sub> = 5 V; I <sub>C</sub> = 0 A	-	-	600	μΑ	
	PDTC123JQB		-	-	180	μΑ	
	PDTC143ZQB		-	-	170	μΑ	
	PDTC114YQB		-	-	150	μΑ	
	PDTC124XQB		-	-	120	μΑ	
h <sub>FE</sub>	DC current gain						
	PDTC143XQB	V <sub>CE</sub> = 5 V; I <sub>C</sub> = 10 mA	50	-	-	T	
	PDTC123JQB		100	-	-		
	PDTC143ZQB		100	-	-		
	PDTC114YQB	V <sub>CE</sub> = 5 V; I <sub>C</sub> = 5 mA	100	-	-		
	PDTC124XQB		80	-	-		
V <sub>CEsat</sub>	collector-emitter saturati	ıtion voltage					
	PDTC143XQB	I <sub>C</sub> = 10 mA; I <sub>B</sub> = 0.5 mA	-	-	100	mV	
	PDTC123JQB	I <sub>C</sub> = 5 mA; I <sub>B</sub> = 0.25 mA	-	-	100	mV	
	PDTC143ZQB		-	-	100	mV	
	PDTC114YQB		-	-	100	mV	
	PDTC124XQB	I <sub>C</sub> = 10 mA; I <sub>B</sub> = 0.5 mA	-	-	100	mV	
V <sub>I(off)</sub>	off-state input voltage						
	PDTC143XQB	V <sub>CE</sub> = 5 V ; I <sub>C</sub> = 100 μA	-	0.8	0.3	V	
	PDTC123JQB		-	0.6	0.5	V	
	PDTC143ZQB		-	0.6	0.5	V	
	PDTC114YQB		-	0.7	0.5	V	
	PDTC124XQB		-	0.8	0.5	V	
V <sub>I(on)</sub>	on-state input voltage		1 1	1			
	PDTC143XQB	V <sub>CE</sub> = 0.3 V ; I <sub>C</sub> = 20 mA	2.5	1.5	-	V	
	PDTC123JQB	V <sub>CE</sub> = 0.3 V ; I <sub>C</sub> = 5 mA	1.1	0.75	-	V	
	PDTC143ZQB	V <sub>CE</sub> = 0.3 V ; I <sub>C</sub> = 5 mA	1.3	0.9	-	V	
	PDTC114YQB	V <sub>CE</sub> = 0.3 V ; I <sub>C</sub> = 1 mA	1.4	0.8	-	V	
	PDTC124XQB	V <sub>CE</sub> = 0.3 V ; I <sub>C</sub> = 2 mA	2.0	1.1	-	V	

50 V, 100 mA NPN resistor-equipped transistors

Symbol	Parameter	Conditions		Min	Тур	Max	Unit		
R1	bias resistor 1 (input)	bias resistor 1 (input)							
	PDTC143XQB		[1]	3.3	4.7	6.1	kΩ		
	PDTC123JQB			1.54	2.2	2.86	kΩ		
	PDTC143ZQB			3.3	4.7	6.1	kΩ		
	PDTC114YQB			7	10	13	kΩ		
PDTC124XQB			15		22	28.6	kΩ		
R2/R1	bias resistor ratio								
	PDTC143XQB		[1]	1.7	2.13	2.6			
	PDTC123JQB			17	21	26			
	PDTC143ZQB			8	10	12			
	PDTC114YQB			3.7	4.7	5.7			
	PDTC124XQB			1.7	2.13	2.6			
f⊤	transition frequency	V <sub>CE</sub> = 5 V; I <sub>C</sub> = 10 mA; f = 100 MHz	[2]	-	230	-	MHz		
C <sub>c</sub>	collector capacitance	V <sub>CB</sub> = 10 V; I <sub>E</sub> = i <sub>e</sub> = 0 A; f = 1 MHz		-	-	2.5	pF		

- [1] See "Section 11: Test information" for resistor calculation and test conditions
- [2] Characteristics of built-in transistor

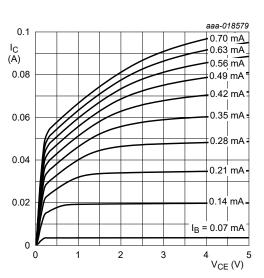


(1) 
$$T_{amb} = 100 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

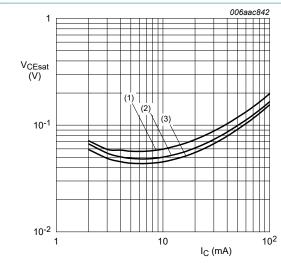
(3) 
$$T_{amb} = -40 \, ^{\circ}C$$

Fig. 4. PDTC143XQB: DC current gain as a function of collector current; typical values



T<sub>amb</sub> = 25 °C

Fig. 5. PDTC143XQB: Collector current as a function of collector-emitter voltage; typical values

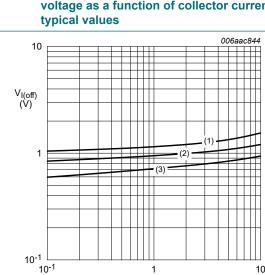


$$I_{\rm C}/I_{\rm B} = 20$$

(1) 
$$T_{amb}$$
 = 100 °C

(3) 
$$T_{amb} = -40 \, ^{\circ}C$$

PDTC143XQB: Collector-emitter saturation Fig. 6. voltage as a function of collector current; typical values



$$V_{CE} = 5 V$$

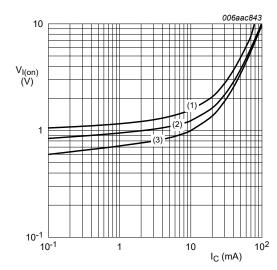
(1) 
$$T_{amb} = -40 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = 100 \, ^{\circ}C$$

PDTC143XQB: Off-state input voltage as a Fig. 8. function of collector current; typical values

I<sub>C</sub> (mA)



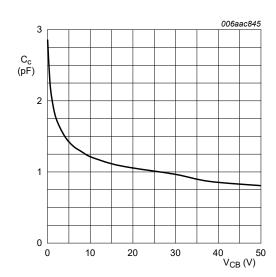
$$V_{CE} = 0.3 V$$

(1) 
$$T_{amb} = -40 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

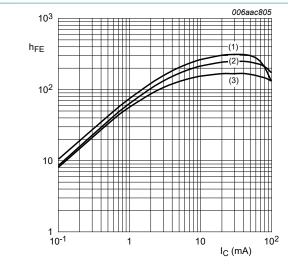
(3) 
$$T_{amb} = 100 \, ^{\circ}C$$

Fig. 7. PDTC143XQB: On-state input voltage as a function of collector current; typical values



$$f = 1 MHz$$

PDTC143XQB: Collector capacitance as a Fig. 9. function of collector-base voltage; typical values

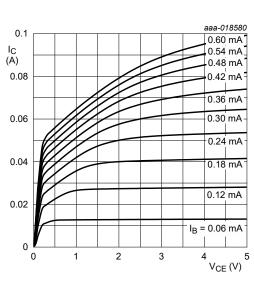


$$V_{CE} = 5 V$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

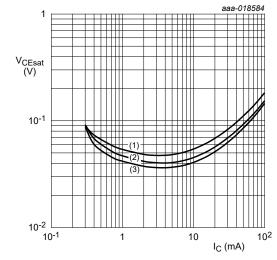
(3) 
$$T_{amb} = -40 \, ^{\circ}C$$

Fig. 10. PDTC123JQB: DC current gain as a function of collector current; typical values



 $T_{amb}$  = 25 °C

Fig. 11. PDTC123JQB: Collector current as a function of collector-emitter voltage; typical values



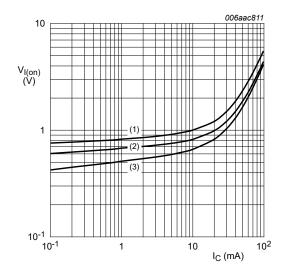
$$I_{\rm C}/I_{\rm B} = 20$$

$$(1) T_{amb} = 100 °C$$

(2) 
$$T_{amb}$$
 = 25 °C

(3) 
$$T_{amb} = -40 \, ^{\circ}C$$

Fig. 12. PDTC123JQB: Collector-emitter saturation voltage as a function of collector current; typical values



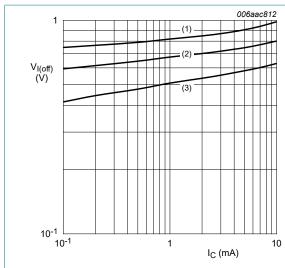
$$V_{CE} = 0.3 \text{ V}$$

(1) 
$$T_{amb} = -40 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = 100 \, ^{\circ}C$$

Fig. 13. PDTC123JQB: On-state input voltage as a function of collector current; typical values

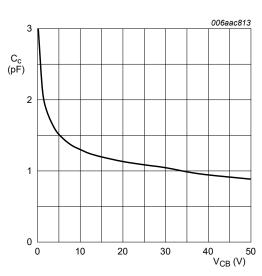


$$V_{CE} = 5 V$$

(1) 
$$T_{amb} = -40 \, ^{\circ}C$$

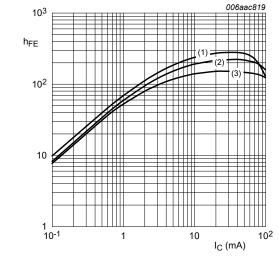
(3) 
$$T_{amb}$$
 = 100 °C

Fig. 14. PDTC123JQB: Off-state input voltage as a function of collector current; typical values



$$T_{amb}$$
 = 25 °C

Fig. 15. PDTC123JQB: Collector capacitance as a function of collector-base voltage; typical values

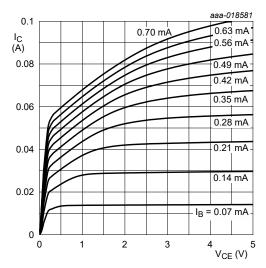


$$V_{CE} = 5 V$$

(1) 
$$T_{amb} = 100 \, ^{\circ}C$$

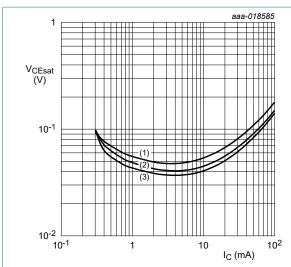
(3) 
$$T_{amb} = -40 \, ^{\circ}C$$

Fig. 16. PDTC143ZQB: DC current gain as a function of collector current; typical values



T<sub>amb</sub> = 25 °C

Fig. 17. PDTC143ZQB: Collector current as a function of collector-emitter voltage; typical values



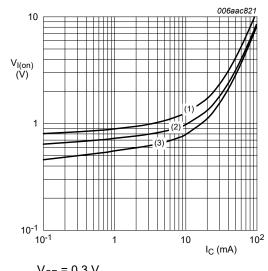
$$I_{\rm C}/I_{\rm B} = 20$$

(1) 
$$T_{amb}$$
 = 100 °C

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = -40 \, ^{\circ}C$$

Fig. 18. PDTC143ZQB: Collector-emitter saturation voltage as a function of collector current; typical values



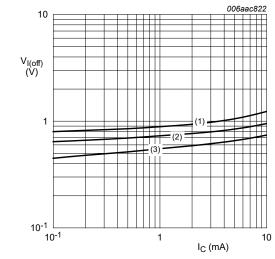
$$V_{CE} = 0.3 V$$

(1) 
$$T_{amb} = -40 \, ^{\circ}C$$

(2) 
$$T_{amb}$$
 = 25 °C

(3) 
$$T_{amb} = 100 \, ^{\circ}C$$

Fig. 19. PDTC143ZQB: On-state input voltage as a function of collector current; typical values



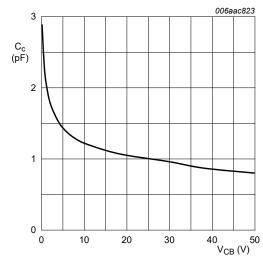
$$V_{CE} = 5 V$$

(1) 
$$T_{amb} = -40 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

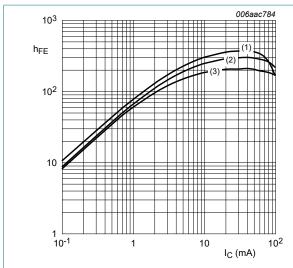
(3) 
$$T_{amb} = 100 \, ^{\circ}C$$

Fig. 20. PDTC143ZQB: Off-state input voltage as a function of collector current; typical values



f = 1 MHz

Fig. 21. PDTC143ZQB: Collector capacitance as a function of collector-base voltage; typical values

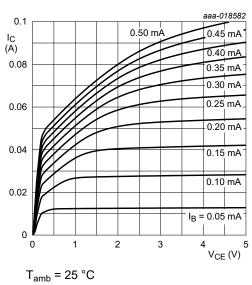


$$V_{CE} = 5 V$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

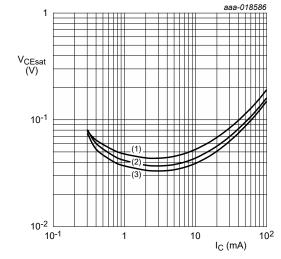
(3) 
$$T_{amb} = -40 \, ^{\circ}C$$

Fig. 22. PDTC114YQB: DC current gain as a function of collector current; typical values



ramb 20 0

Fig. 23. PDTC114YQB: Collector current as a function of collector-emitter voltage; typical values



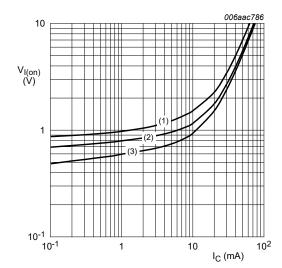
$$I_C/I_B = 20$$

(1) 
$$T_{amb} = 100 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = -40 \, ^{\circ}C$$

Fig. 24. PDTC114YQB: Collector-emitter saturation voltage as a function of collector current; typical values



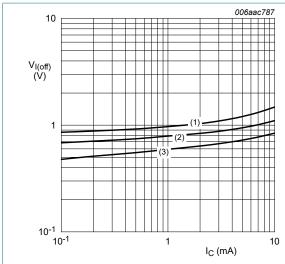
$$V_{CE} = 0.3 V$$

(1) 
$$T_{amb} = -40 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = 100 \, ^{\circ}C$$

Fig. 25. PDTC114YQB: On-state input voltage as a function of collector current; typical values



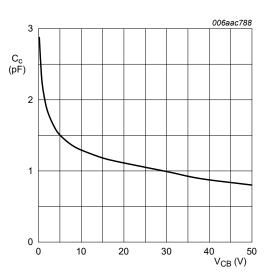
$$V_{CE} = 5 V$$

(1) 
$$T_{amb} = -40 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb}$$
 = 100 °C

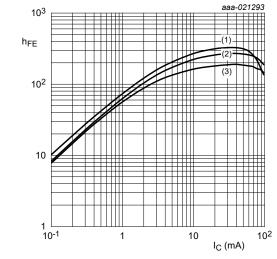
Fig. 26. PDTC114YQB: Off-state input voltage as a function of collector current; typical values



$$f = 1 MHz$$

$$T_{amb}$$
 = 25 °C

Fig. 27. PDTC114YQB: Collector capacitance as a function of collector-base voltage; typical values



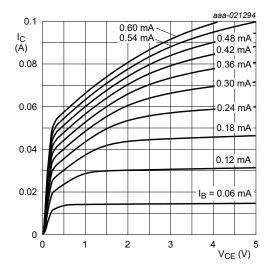
 $V_{CE} = 5 V$ 

$$(1) T_{amb} = 100 °C$$

(2) 
$$T_{amb}$$
 = 25 °C

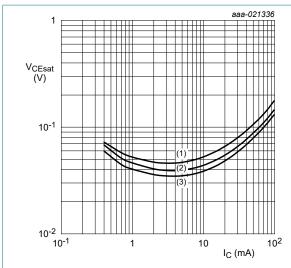
(3) 
$$T_{amb} = -40 \, ^{\circ}C$$

collector current; typical values



T<sub>amb</sub> = 25 °C

Fig. 28. PDTC124XQB: DC current gain as a function of Fig. 29. PDTC124XQB: Collector current as a function of collector-emitter voltage; typical values

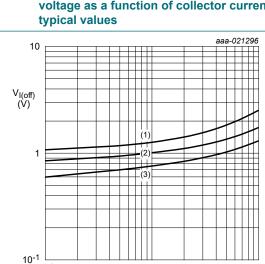


$$I_C/I_B = 20$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = -40 \, ^{\circ}C$$

Fig. 30. PDTC124XQB: Collector-emitter saturation voltage as a function of collector current;



$$V_{CE} = 5 V$$

10<sup>-1</sup>

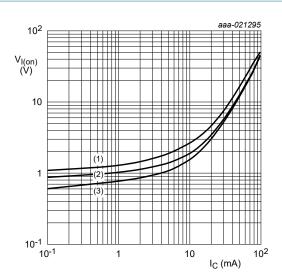
(1) 
$$T_{amb} = -40 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = 100 \, ^{\circ}C$$

Fig. 32. PDTC124XQB: Off-state input voltage as a function of collector current; typical values

I<sub>C</sub> (mA)



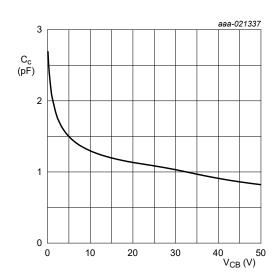
$$V_{CE} = 0.5 V$$

(1) 
$$T_{amb} = -40 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

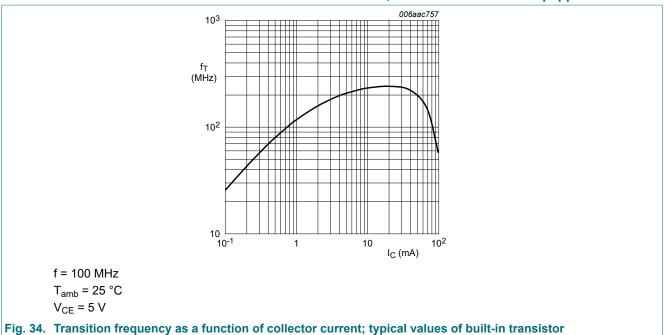
(3) 
$$T_{amb} = 100 \, ^{\circ}C$$

Fig. 31. PDTC124XQB: On-state input voltage as a function of collector current; typical values



f = 1 MHz

Fig. 33. PDTC124XQB: Collector capacitance as a function of collector-base voltage; typical values



# 11. Test information

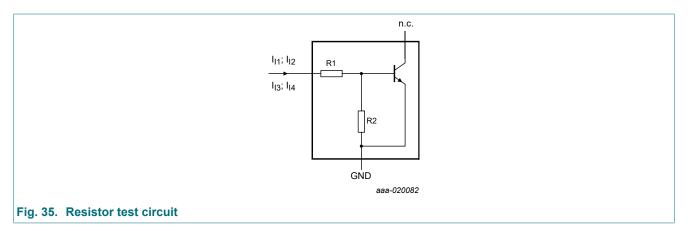
#### **Resistor calculation**

• Calculation of bias resistor 1 (R1)

$$R1 = \frac{V(I_{12}) - V(I_{11})}{I_{12} - I_{11}}$$

· Calculation of bias resistor ratio (R2/R1)

$$\frac{R2}{R1} = \frac{V(I14) - V(I13)}{R1 \cdot (I14 - I13)} - 1$$

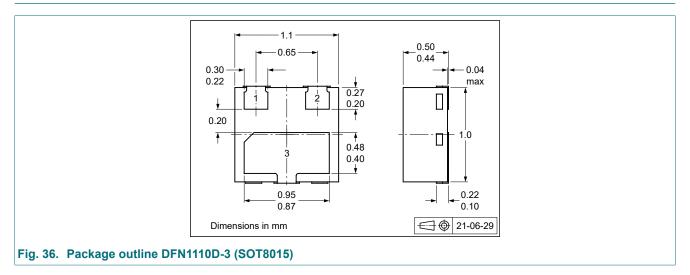


### Resistor test conditions

Table 9. Resistor test conditions

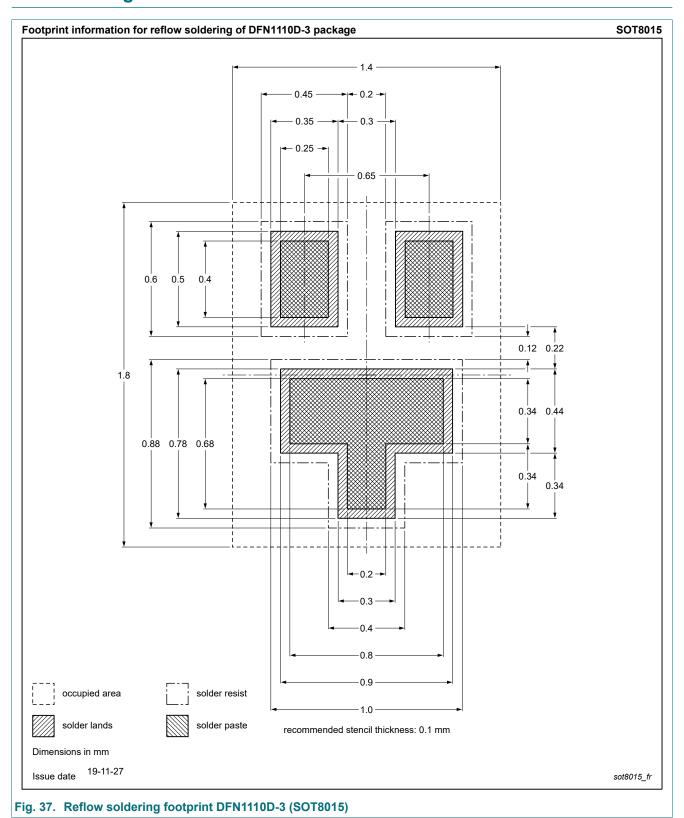
Type number	R1 (kΩ)	R2 (kΩ)	Test conditi			
			I <sub>I1</sub>	I <sub>I2</sub>	I <sub>I3</sub>	I <sub>14</sub>
PDTC143XQB	4.7	10	350 μΑ	450 µA	-350 µA	-450 μA
PDTC123JQB	2.2	47	90 µA	140 µA	-55 µA	-105 μA
PDTC143ZQB	4.7	47	90 µA	140 µA	-55 μA	-105 μA
PDTC114YQB	10	47	90 μΑ	140 µA	-55 μA	-105 μA
PDTC124XQB	22	47	55 µA	105 μΑ	-55 µA	-105 μA

# 12. Package outline



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# 13. Soldering



# 14. Revision history

#### Table 10. Revision history

Data sheet ID	Release date		Change notice	Supersedes
PDTC143X_TO_124XQB_SER v.1	20211001	Product data sheet	-	-

### 15. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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Date of release: 1 October 2021

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